

CMOS 14-STAGE COUNTER AND OSCILLATOR

FEATURES

- ◆ 14 Fully Static Stages
- ◆ 10 Buffered Outputs Available
- ◆ Common Reset Line
- ◆ 8MHz Counting Rate @ 10Vdc
- ◆ All Active Oscillator Components on Chip for R-C or Crystal Control

DESCRIPTION

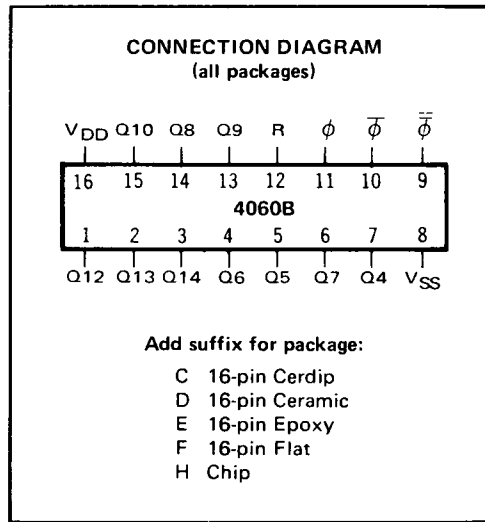
The 4060 B consists of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either R-C or crystal oscillator circuits. A Reset input is provided which resets the counter to the all-0's state. A high level on the Reset line accomplishes the reset function. The state of the counter is advanced one step in binary order on the negative transition of the Clock input ϕ . All inputs and outputs are fully buffered. Outputs are available from stages 4 through 10 and 12 through 14.

Applications include timers, frequency dividers, delay circuits and counter controls.

TRUTH TABLE

CLOCK	RESET	OUTPUT STATE
	0	No Change
	0	Advance to next state
X	1	All Outputs are low

X = Don't Care

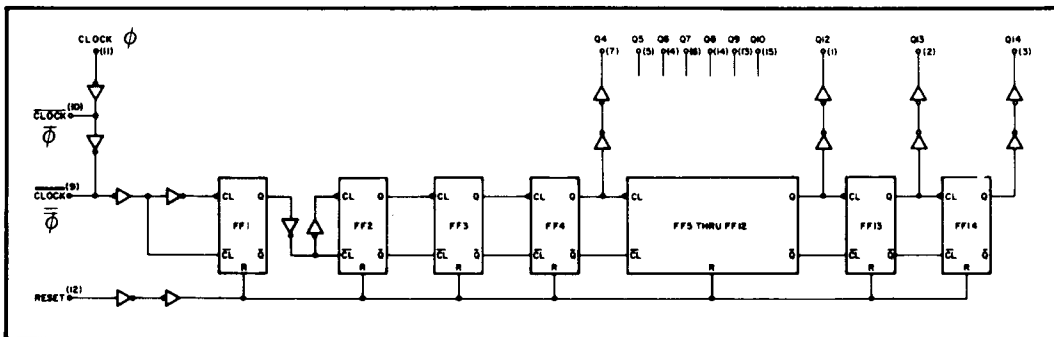


RECOMMENDED OPERATING CONDITIONS

For maximum reliability:

- DC Supply Voltage $V_{DD} - V_{SS}$ 3 to 15 V_0
- Operating Temperature T_A
- C, D, F, H Device -55 to +125 °C
- E Device -40 to +85 °C

LOGIC DIAGRAM



ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS¹

PARAMETER	V _{DD} (Vdc)	CONDITIONS	T _{LOW} ²		+25°C			T _{HIGH} ²		Units
			Min.	Max.	Min.	Typ.	Max.	Min.	Max.	
QUIESCENT DEVICE CURRENT	I _{DD}	V _{IN} = V _{SS} or V _{DD} All valid input combinations	–	5	–	0.05	5	–	150	μA _{dc}
			–	10	–	0.1	10	–	300	
			–	20	–	0.2	20	–	600	

NOTES: ¹ Remaining Static Electrical Characteristics are listed under "4000B Series Family Specifications".

² T_{LOW} = –55°C for C, D, F, H device.

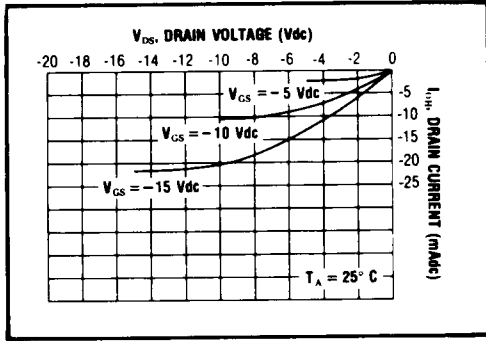
= –40°C for E device.

T_{HIGH} = +125°C for C, D, F, H device.

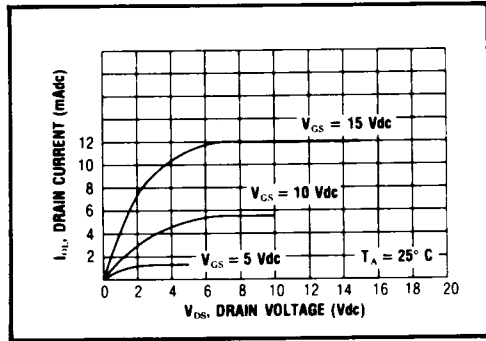
= +85°C for E device.

DYNAMIC CHARACTERISTICS (C_L = 50pF, T_A = 25°C)

PARAMETER	V _{DD} (Vdc)	Min.	Typ.	Max.	Units
CLOCKED OPERATION					
PROPAGATION DELAY TIME Clock to Q4	t _{PLH} , t _{PHL}	5	–	400	ns
		10	–	200	
		15	–	150	
Q _i to Q _i + 1	t _{PLH} , t _{PHL}	5	–	100	ns
		10	–	40	
		15	–	30	
OUTPUT TRANSITION TIME	t _{TLH} , t _{THL}	5	–	100	ns
		10	–	40	
		15	–	30	
MINIMUM CLOCK PULSE WIDTH	PW _{CL}	5	–	70	ns
		10	–	30	
		15	–	20	
MAXIMUM CLOCK FREQUENCY	f _{CL}	5	3.0	4.5	MHz
		10	6.0	9.0	
		15	7.5	11.0	
MAXIMUM CLOCK RISE AND FALL TIME	t _{rCL} , t _{fCL}	5	50	100	μs
		10	50	100	
		15	50	100	
RESET OPERATION					
PROPAGATION DELAY TIME	t _{PHL}	5	–	200	ns
		10	–	100	
		15	–	75	
MINIMUM RESET PULSE WIDTH	PW _R	5	–	100	ns
		10	–	40	
		15	–	30	
RESET REMOVAL TIME	t _{rem}	5	–	150	ns
		10	–	65	
		15	–	40	

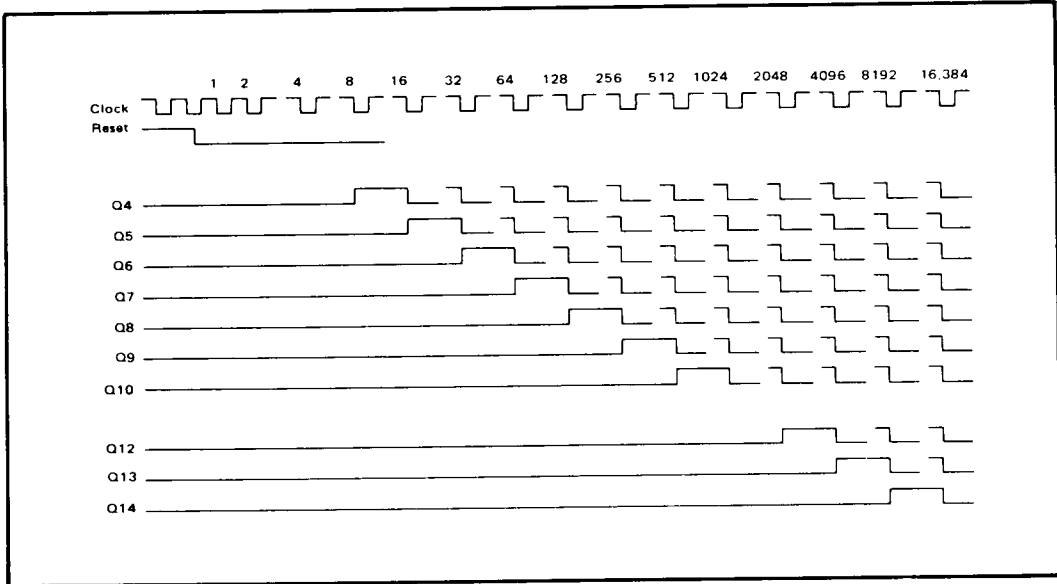


Typical P-Channel Source Current Characteristics

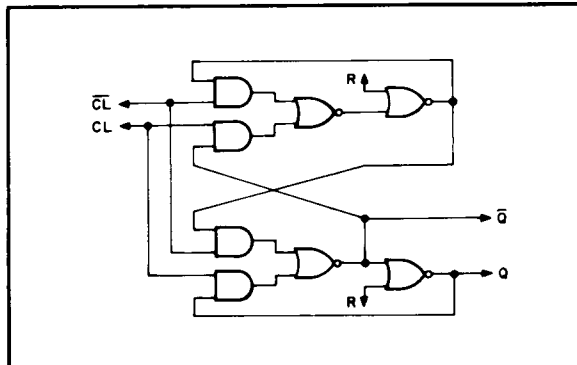


Typical N-Channel Sink Current Characteristics

TIMING DIAGRAM



TYPICAL COUNTER STAGE



APPLICATIONS INFORMATION

TYPICAL COMPONENT VALUES AND CIRCUIT PERFORMANCE

OSCILLATOR FREQUENCY	R _S KΩ	R _T KΩ	C _T	I _{DD} mA @ V _{DD} = 10 V
10 Hz	450	45	1 μF	0.3
100 Hz	450	45	0.1 μF	0.3
1000 Hz	450	45	0.01 μF	0.4
10 KHz	450	45	0.001 μF	0.5
100 KHz	450	45	100 pF	0.7
1 MHz	45	4.5	100 pF	1

Typical RC oscillator circuit

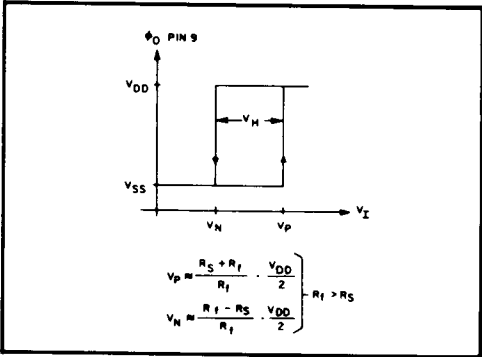
$5M\Omega \leq R_f \leq 100M\Omega$
 $R_S \approx (5X \rightarrow 10X) R_S(XTAL)$
 $\frac{C_S C_T}{C_S + C_T} \approx C_L(XTAL)$

Typical crystal oscillator circuit

TYPICAL COMPONENT VALUES FOR OPERATION FROM 50 Hz INPUT AT V_{DD} = 3 TO 15 VOLTS:
 $R_S = 150 K\Omega$
 $R_1 = 390 K\Omega$

(FOR USE WHEN INPUT SIGNALS WITH SLOW RISE-FALL TIME ARE USED AS CLOCK)

Input pulse-shaping circuit (Schmitt trigger)



Input circuit characteristics for pulse-shaping circuit.